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With the principle of “Quality Parts,Customers Priority,Honest Operation,and Considerate Service”,our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip,ALPS,ROHM,Xilinx,Pulse,ON,Everlight and Freescale. Main products comprise IC,Modules,Potentiometer,IC Socket,Relay,Connector.Our parts cover such applications as commercial,industrial, and automotives areas.

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DESCRIPTION

This UPS360e3 in the Powermite3[®] package is a high efficiency Schottky rectifier that is also RoHS compliant offering high current/power capabilities previously found only in much larger packages. They are ideal for SMD applications that operate at high frequencies. In addition to its size advantages, the Powermite3[®] package includes a full metallic bottom that eliminates the possibility of solder flux entrapment during assembly and a unique locking tab act as an efficient heat path to the heat-sink mounting. Its innovative design makes this device ideal for use with automatic insertion equipment.

KEY FEATURES


- Very low thermal resistance package
- RoHS Compliant with e3 suffix part number
- Guard-ring-die construction for transient protection
- Efficient heat path with Integral locking bottom metal tab
- Low forward voltage
- Full metallic bottom eliminates flux entrapment
- Compatible with automatic insertion
- Low profile-maximum height of 1mm

IMPORTANT: For the most current data, consult MICROSEMI's website: <http://www.microsemi.com>

ABSOLUTE MAXIMUM RATINGS AT 25°C (UNLESS OTHERWISE SPECIFIED)

Rating	Symbol	Value	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V_{RRM} V_{RWM} V_R	60	V
RMS Reverse Voltage	$V_R (RMS)$	42	V
Average Rectified Output Current	I_o	3	A
Non-Repetitive Peak Forward Surge Current 8.3ms Single half sine wave Superimposed on Rated Load	I_{FSM}	100 @ 25°C 50 @ 100°C	A
Storage Temperature	T_{STG}	-55 to +150	°C
Junction Temperature	T_J	-55 to +125	°C

APPLICATIONS/BENEFITS

- Switching and Regulating Power Supplies.
- Silicon Schottky (hot carrier) rectifier for minimal reverse voltage recovery
- Elimination of reverse-recovery oscillations to reduce need for EMI filtering
- Charge Pump Circuits
- Reduces reverse recovery loss with low I_{RM}
- Small foot print 
190 X 270 mils (1:1 Actual size)
See mounting pad details on pg 3

MECHANICAL & PACKAGING

- CASE: Void-free transfer molded thermosetting epoxy compound meeting UL94V-0
- FINISH: Annealed matte-Tin plating over copper and readily solderable per MIL-STD-750 method 2026 (consult factory for Tin-Lead plating)
- POLARITY: See figure (left)
- MARKING: S360•
- WEIGHT: 0.072 gram (approx.)
- Package dimension on last page
- Tape & Reel option: 16 mm tape per Standard EIA-481-B, 5000 on 13" reel

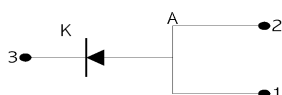
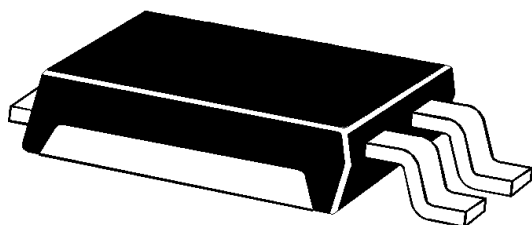
THERMAL CHARACTERISTICS

Thermal Resistance

Junction-to-case (bottom)	$R_{\theta JC}$	3.2	°C/ Watt
Junction to ambient (1)	$R_{\theta JA}$	65	°C/ Watt

(1) When mounted on FR-4 PC board using 2 oz copper with recommended minimum foot print

Powermite 3™



ELECTRICAL PARAMETERS @25°C (unless otherwise specified)

Parameter	Symbol	Conditions	Min	Typ.	Max	Units
Forward Voltage (Note 1)	V_F	$I_F = 3.5 \text{ A}$, $T_J = 25^\circ\text{C}$ $I_F = 3.5 \text{ A}$, $T_J = 125^\circ\text{C}$ $I_F = 7 \text{ A}$, $T_J = 25^\circ\text{C}$ $I_F = 7 \text{ A}$, $T_J = 25^\circ\text{C}$		0.59 0.53 0.72 0.63	0.63 0.57 0.76 0.67	V
Reverse Break Down Voltage (Note 1)	V_{BR}	$I_R = 0.2 \text{ mA}$	60			V
Reverse Current (Note 1)	I_R	$V_R = 60\text{V}$, $T_J = 25^\circ\text{C}$ $V_R = 60\text{V}$, $T_J = 100^\circ\text{C}$ $V_R = 60\text{V}$, $T_J = 125^\circ\text{C}$		2 0.6 2.5	200 20 150	μA mA mA
Capacitance	C_T	$V_R = 4 \text{ V}$; $f = 1 \text{ MHz}$		130		pF

Note: 1 Short duration test pulse used to minimize self-heating effect.

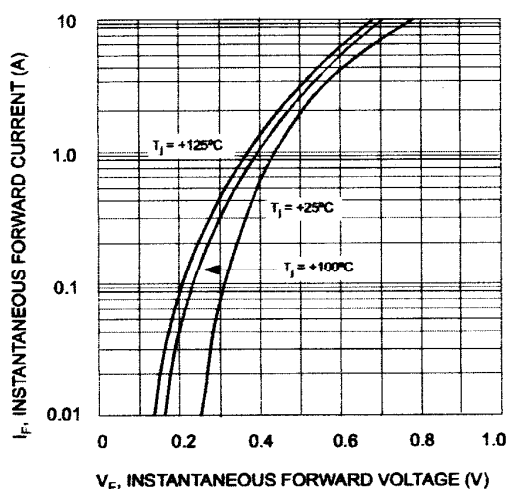


Fig. 1 Typ. Forward Characteristics

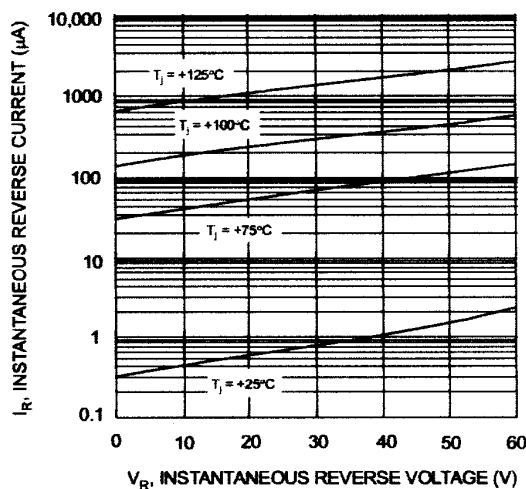


Fig. 2 Typical Reverse Characteristics

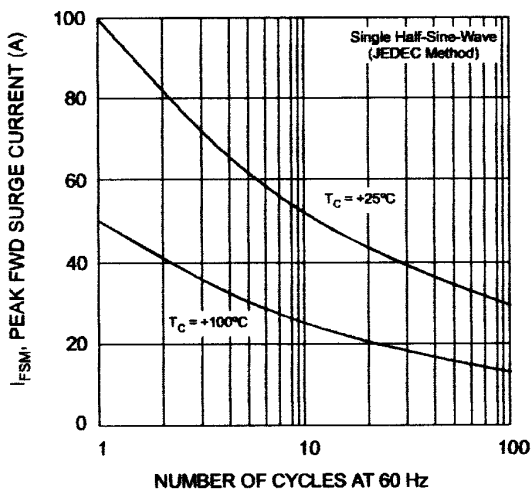


Fig. 3 Max Non-Repetitive Peak Fwd Surge Current

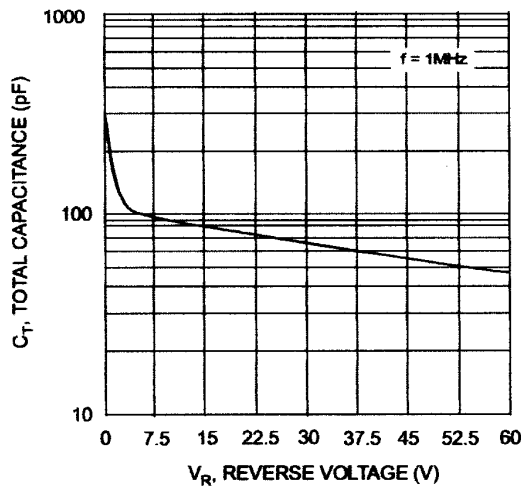
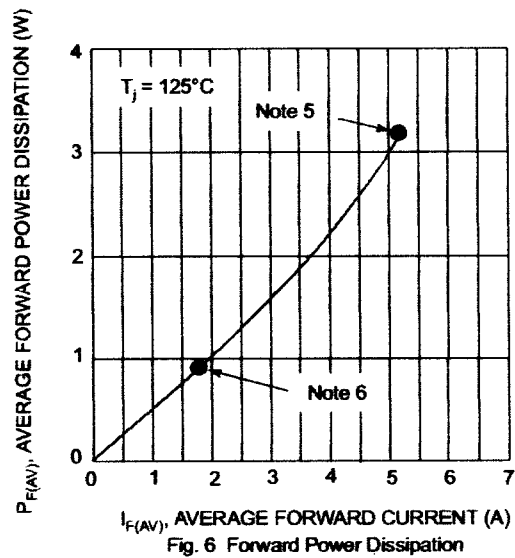
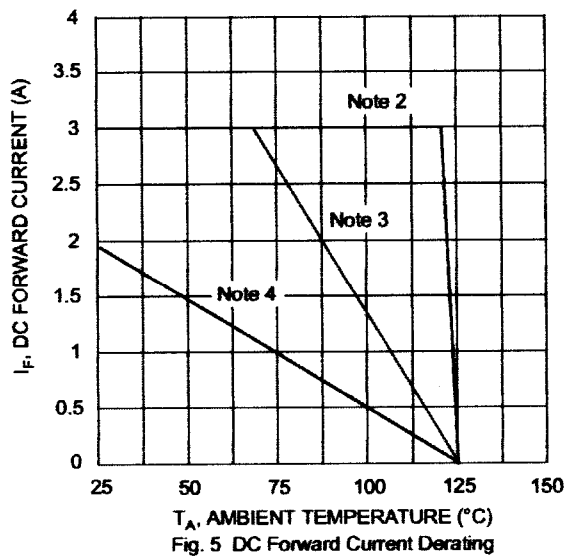
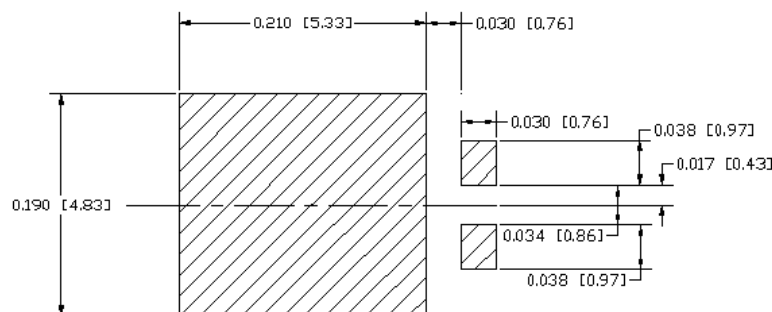


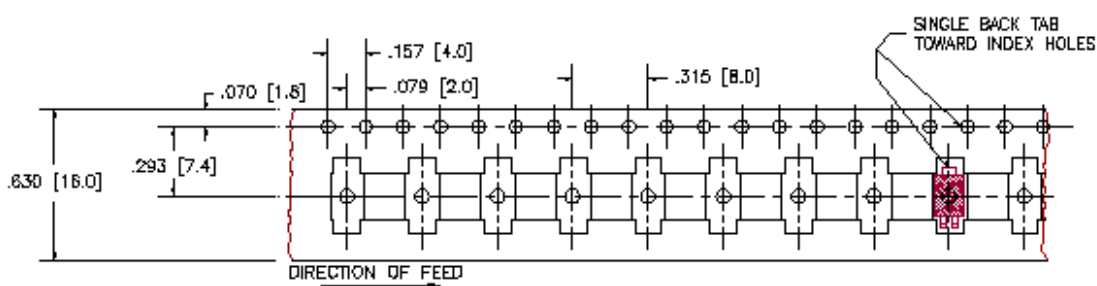
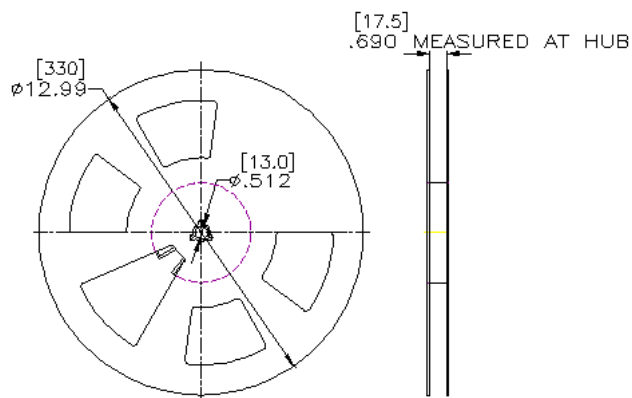
Fig. 4 Typical Capacitance vs. Reverse Voltage

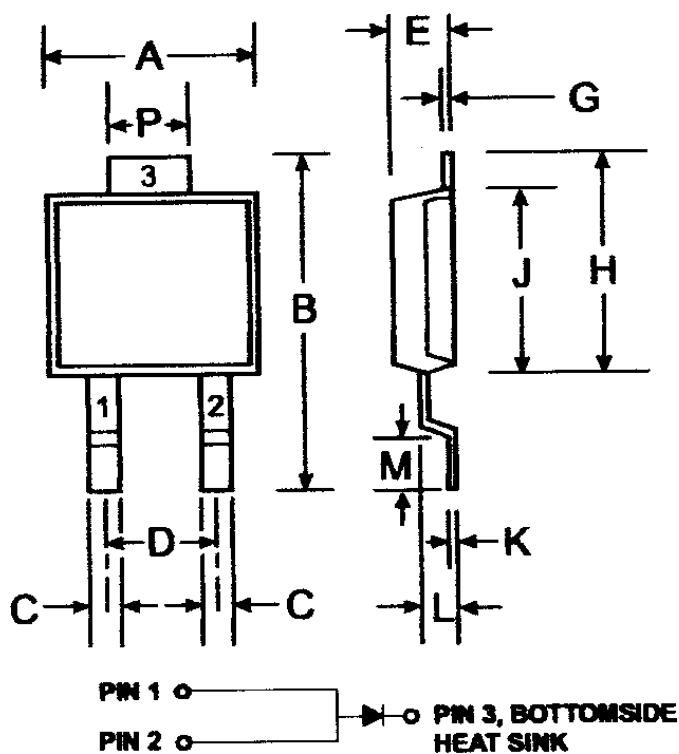


- Notes:
- $T_A = T_{\text{SOLDERING POINT}}$, $R_{\theta JS} = 3.2^\circ\text{C/W}$, $R_{\theta SA} = 0^\circ\text{C/W}$.
 - Device mounted on GETEK substrate, 2" x 2", 2 oz. copper, double-sided, cathode pad dimensions 0.75" x 1.0", anode pad dimensions 0.25" x 1.0". $R_{\theta JA}$ in range of 20-40° C/W.
 - Device mounted on FRA-4 substrate, 2" x 2", 2 oz. copper, single-sided, pad layout $R_{\theta JA}$ in range of 65° C/W. See mounting pad below.
 - Maximum power dissipation when the device is mounted in accordance to the conditions described in Note 3.

PAD LAYOUT inches [mm]



16 mm TAPE

13 INCH REEL


PACKAGE & MOUNTING PAD DIMENSIONS


Note: Pins 1 & 2 must be electrically connected at the printed circuit board.

POWERMITE®3		
Dim	Min	Max
A	4.03	4.09
B	6.40	6.61
C	.889 NOM	
D	1.83 NOM	
E	1.10	1.14
G	.178 NOM	
H	5.01	5.17
J	4.37	4.43
K	.178 NOM	
L	.71	.77
M	.36	.46
P	1.73	1.83
All Dimensions in mm		